

Product Document

TSL238T

High-Sensitivity Light-to-Frequency Converter

General Description

The TSL238T light-to-frequency converter combines a silicon photodiode and a current-to-frequency converter on a single monolithic CMOS integrated circuit. Output is a square wave (50% duty cycle) with frequency directly proportional to light intensity (irradiance) on the photodiode. The digital output allows direct interface to a microcontroller or other logic circuitry. Output enable (\overline{OE}) places the output in a high-impedance state for multiple-unit sharing of a microcontroller input line. The device has been temperature compensated for the ultraviolet-to-visible light range of 320 nm to 700 nm and responds over the light range of 320 nm to 1050 nm. The TSL238T is characterized for operation over the temperature range of -40°C to 85°C and is supplied in a compact 4-lead surface-mount package that is lead (Pb) free and RoHS compliant.

Ordering Information and Content Guide appear at end of datasheet.

Key Benefits & Features

The benefits and features of TSL238T, High-Sensitivity Light-to-Frequency Converter are listed below:

Figure 1:
Added Value Of Using TSL238T

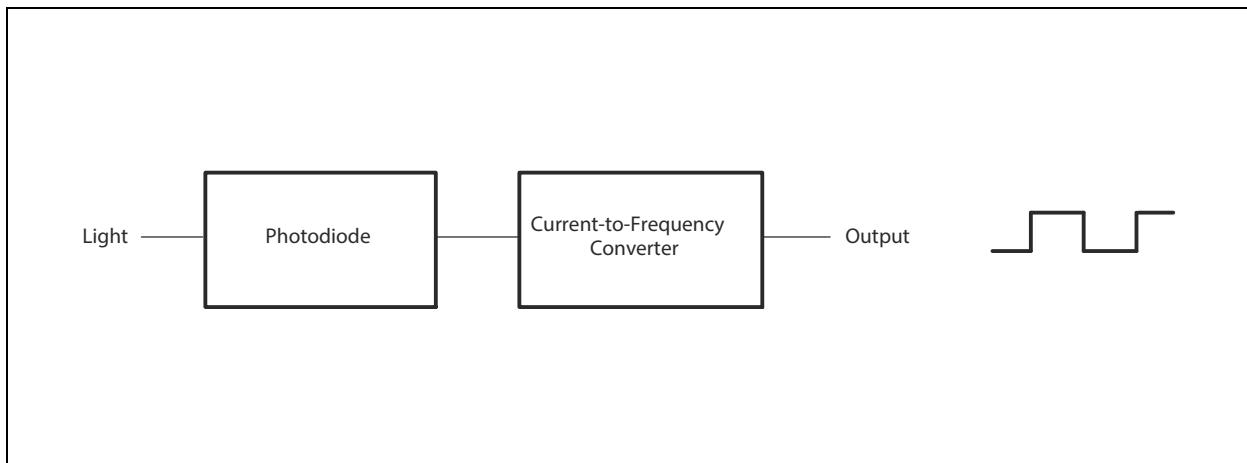
Benefits	Features
<ul style="list-style-type: none"> • Detects Light Intensity at a High Resolution 	<ul style="list-style-type: none"> • 850K:1 Input Dynamic Range
<ul style="list-style-type: none"> • Provides Low Light Level Operation 	<ul style="list-style-type: none"> • Low Dark Frequency <6Hz at 50°C
<ul style="list-style-type: none"> • Reduces Board Space Requirements While Simplifying Designs 	<ul style="list-style-type: none"> • 2.6mm x 3.8mm 4-Lead SMD (T) Package

- High-Resolution Conversion of Light Intensity to Frequency With No External Components
- High Irradiance Responsivity $3.4\text{kHz}/(\mu\text{W}/\text{cm}^2)$ at $\lambda_p=640\text{nm}$
- Single-Supply Operation 2.7 V to 5.5 V
- Stable 200 ppm/°C Temperature Coefficient
- Interfaces Directly to a Microcontroller

Functional Block Diagram

The functional blocks of this device are shown below:

Figure 2:
TSL238T Block Diagram



Pin Assignments

Figure 3:
Package T 4-Lead SMD (Top View)

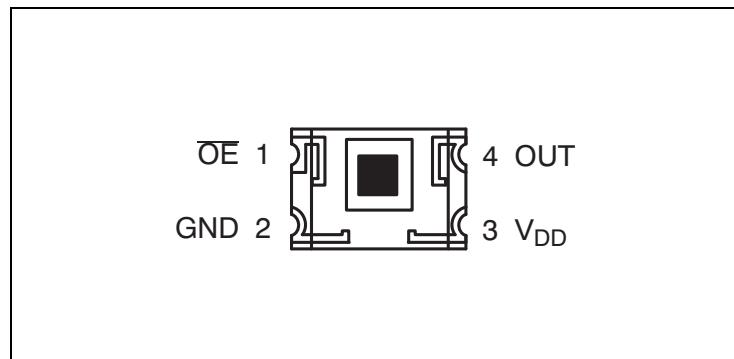


Figure 4:
Terminal Functions

Terminal		Type	Description
Name	T PKG No.		
GND	2		Power supply ground (substrate). All voltages are referenced to GND.
\overline{OE}	1	I	Enable for f_O (active low).
OUT	4	O	Output frequency.
V_{DD}	3		Supply voltage.

Absolute Maximum Ratings

Stresses beyond those listed under **Absolute Maximum Ratings** may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under **Recommended Operating Conditions** is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Figure 5:
Absolute Maximum Ratings Over Operating Free-Air Temperature Range (unless otherwise noted)

Symbol	Parameter	Min	Max	Units
V_{DD}	Supply voltage ⁽¹⁾		6	V
V_I	Input voltage range	-0.3	$V_{DD}+0.3$	V
I_O	Output current		± 5	mA
	Short circuit of output to ground duration		5	s
T_A	Operating free-air temperature range ⁽²⁾	-40	85	°C
T_{stg}	Storage temperature range ⁽²⁾	-40	85	°C
	Solder conditions in accordance with JEDEC J-STD-020C		260	°C

Note(s):

1. All voltages are with respect to GND.
2. Long-term storage or operation above 70°C could cause package yellowing that will lower the sensitivity to wavelengths < 500nm.

Figure 6:
Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V_{DD}	Supply voltage	2.7	5	5.5	V
V_{IH}	High-level input voltage	$0.8 \times V_{DD}$		V_{DD}	V
V_{IL}	Low-level input voltage	0		0.5	V
T_A	Operating free-air temperature range	-40		70	°C

Electrical Characteristics

Figure 7:

Electrical Characteristics at $V_{DD} = 5$ V, $T_A = 25^\circ\text{C}$, $\lambda_p = 640\text{nm}$ ⁽¹⁾ (unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{OH}	High-level output voltage	$I_{OH} = -1$ mA	4	4.5		V
V_{OL}	Low-level output voltage	$I_{OL} = 1$ mA		0.25	0.4	V
I_{IH}	High-level input current		-10		10	μA
I_{IL}	Low-level input current		-10		10	μA
I_{DD}	Supply current	$E_e = 14.7 \mu\text{W}/\text{cm}^2$		2	3	mA
	Full-scale frequency ⁽²⁾	$T_A = 50^\circ\text{C}$ ⁽³⁾	500		1000	kHz
	Temperature coefficient of responsivity	Wavelength < 600nm, $f_O = 50$ kHz		± 200		ppm/ $^\circ\text{C}$
k_{SVS}	Supply-voltage sensitivity	$V_{DD} = 5$ V $\pm 10\%$		± 0.5		%/V

Note(s):

1. The input irradiance is supplied with red LED light source with peak wavelength = 640 nm.
2. Full-scale frequency is the maximum frequency of the device without saturation. Higher irradiance will not result in any additional increase of output frequency. The output frequency will remain at approximately the saturation frequency to a minimum of 1000 $\mu\text{W}/\text{cm}^2$ 640nm irradiance. During production testing, devices are not tested at this very high irradiance level.
3. Measured at wafer probe using 50°C hot chuck.

Figure 8:Operating Characteristics at $V_{DD} = 5$ V, $T_A = 25^\circ\text{C}$, $\lambda_p = 640$ nm (unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
f_O	Output frequency	$E_e = 14.7 \mu\text{W}/\text{cm}^2$	40	50	60	kHz
f_D	Dark frequency	$E_e = 0 \mu\text{W}/\text{cm}^2$	0	0.3		Hz
		$E_e = 0 \mu\text{W}/\text{cm}^2, T_A = 50^\circ\text{C}$ (1)	0		6	Hz
R_e	Irradiance responsivity		3.4			$\text{kHz}/(\mu\text{W}/\text{cm}^2)$
λ_p	Peak response wavelength		700			nm
	Nonlinearity (2)	$f_O = 0$ kHz to 10 kHz	$\pm 1\%$			%F.S.
	Step response to full-scale step input		1 pulse of new frequency plus 1 μs			
	Time from $\overline{\text{OE}}$ low to output enabled		1 period of output frequency			

Note(s):

1. Measured at wafer probe using 50°C hot chuck.
2. Nonlinearity is defined as the deviation from a straight line between zero and maximum of stated range, expressed as a percent of stated range.

Typical Characteristics

Figure 9:
Output Frequency vs Irradiance

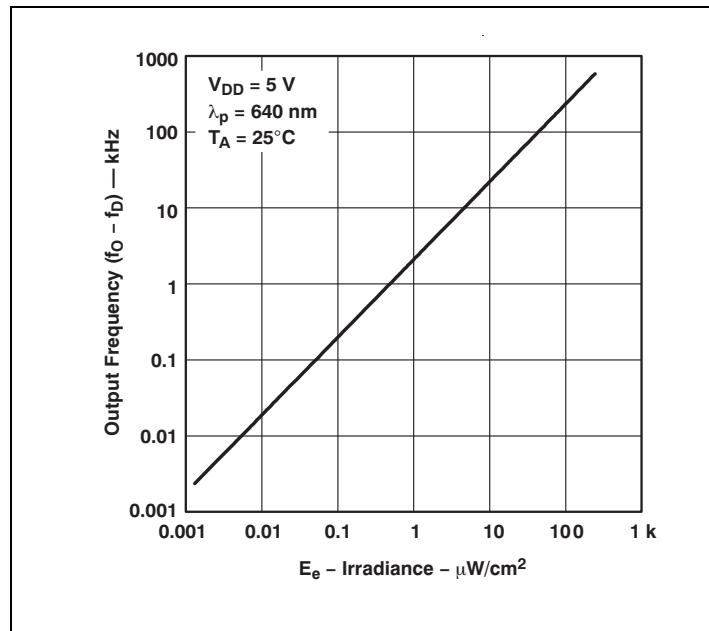


Figure 10:
Photodiode Spectral Responsivity

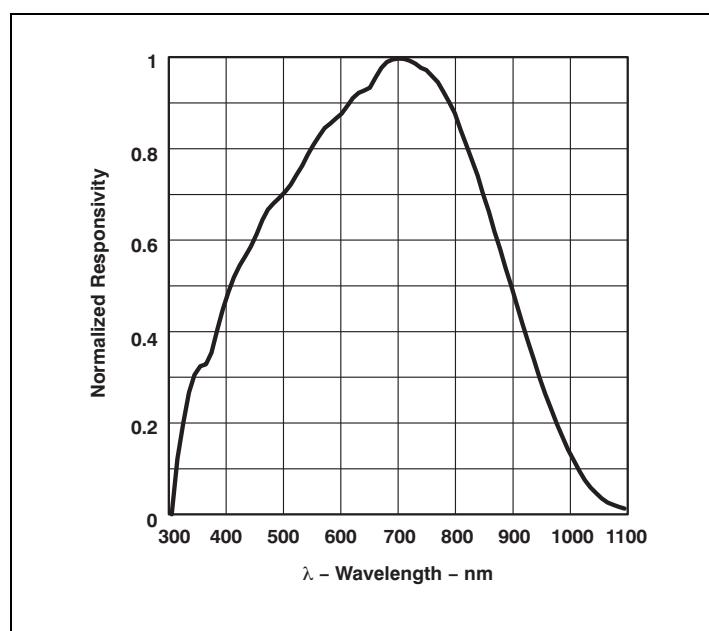


Figure 11:
Supply Current vs. Free-Air Temperature

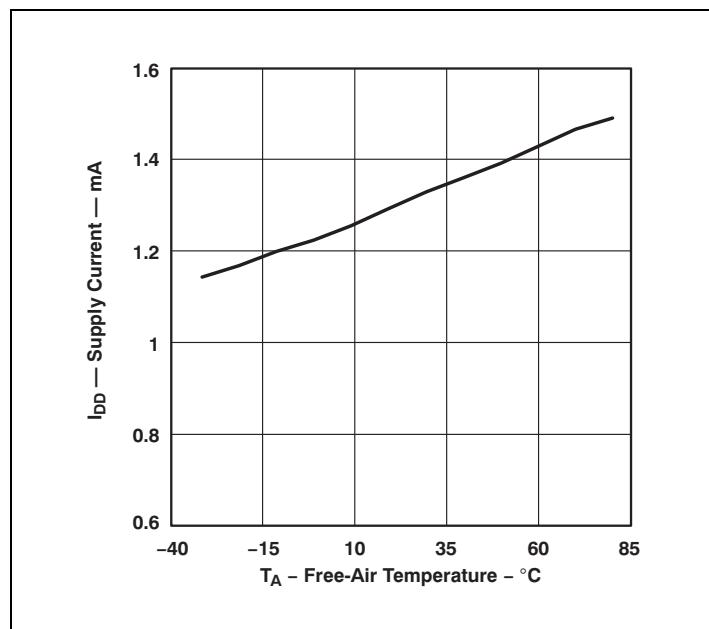


Figure 12:
Output Frequency vs. Free-Air Temperature

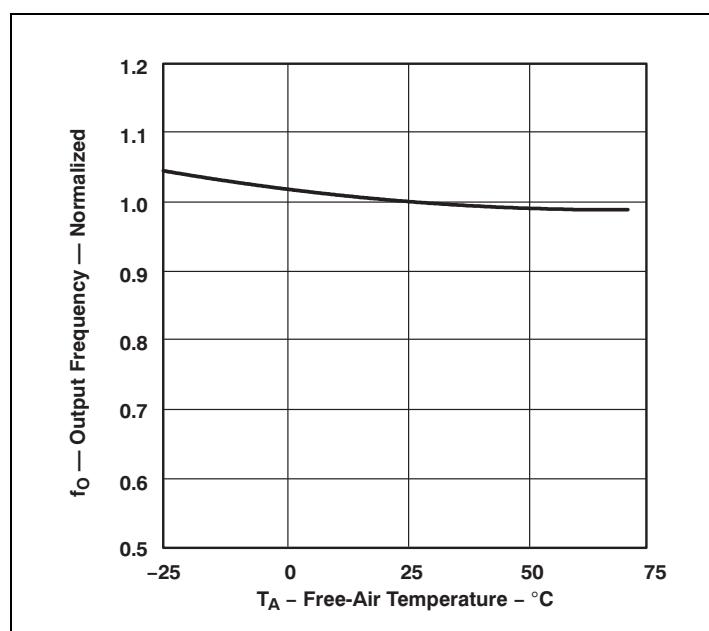


Figure 13:
Normalized Output Voltage vs. Angular Displacement

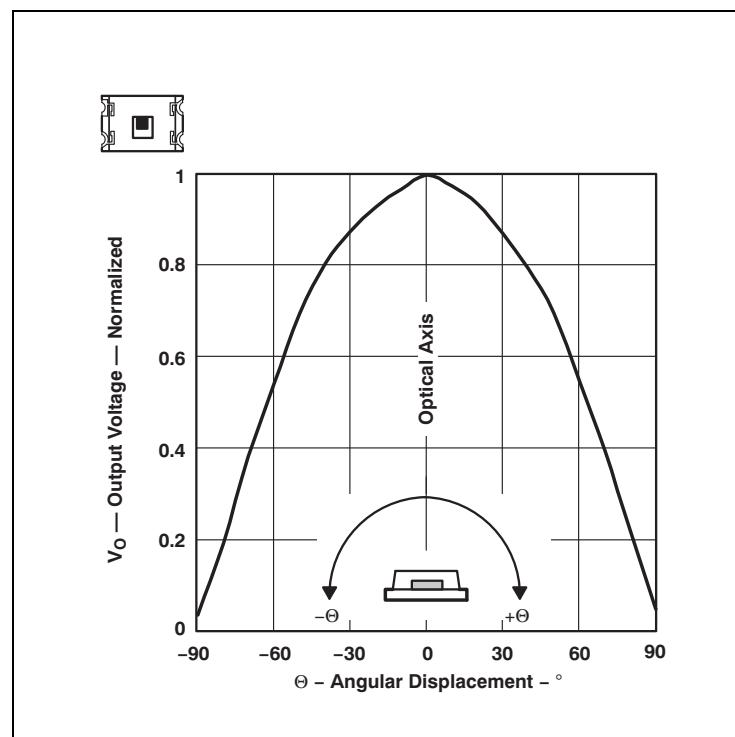


Figure 14:
Normalized Output Voltage vs. Angular Displacement

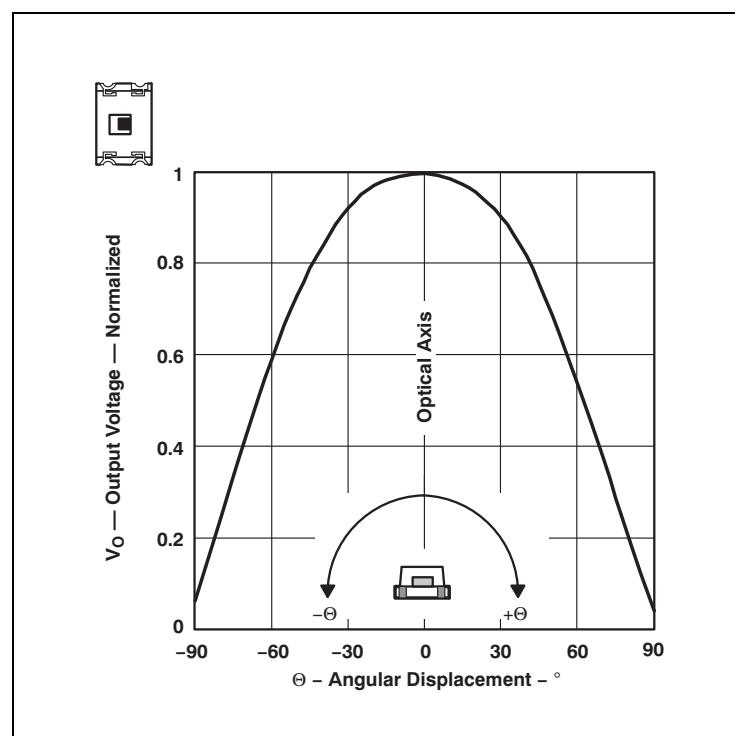
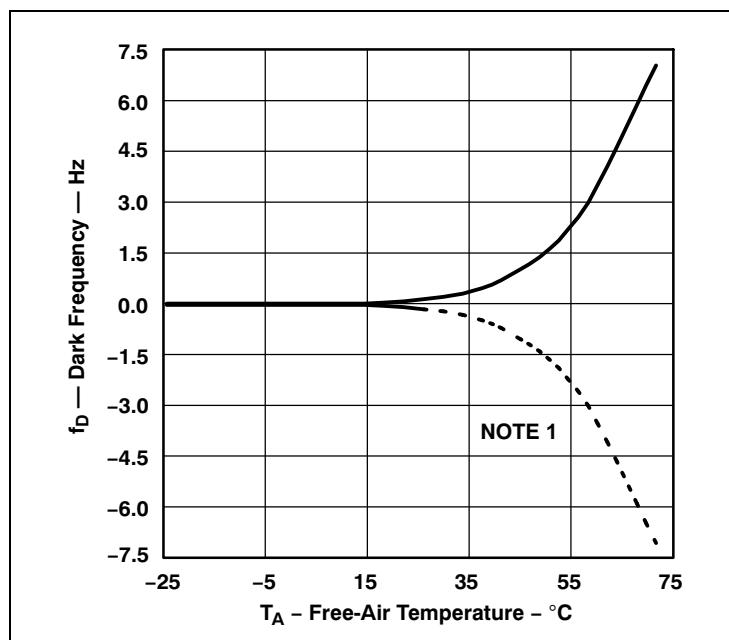


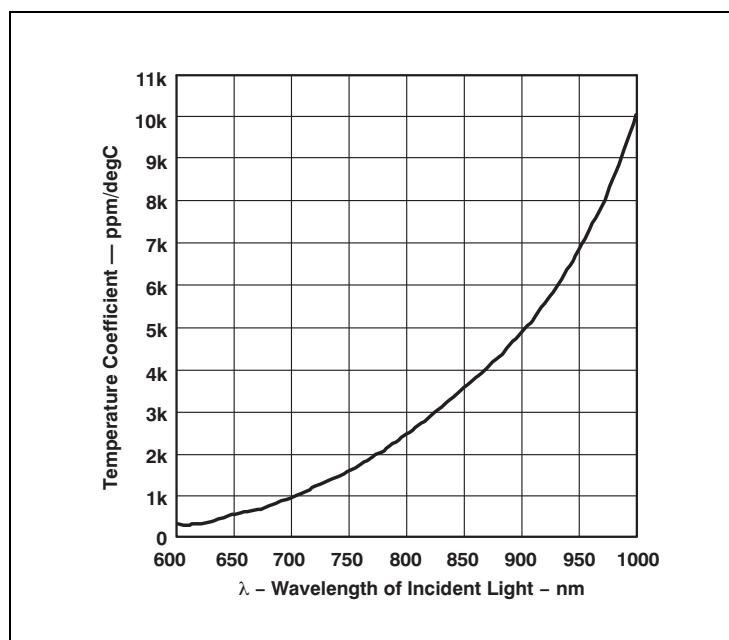
Figure 15:
Dark Frequency vs. Free-Air Temperature



Note(s):

1. Internal offsets that result in dark frequency can be both positive and negative. The dashed line represents the case of negative offset in which an equivalent amount of light signal is required to obtain a non-zero output frequency.

Figure 16:
Photodiode Responsivity Temperature Coefficient Vs.
Wavelength of Incident Light

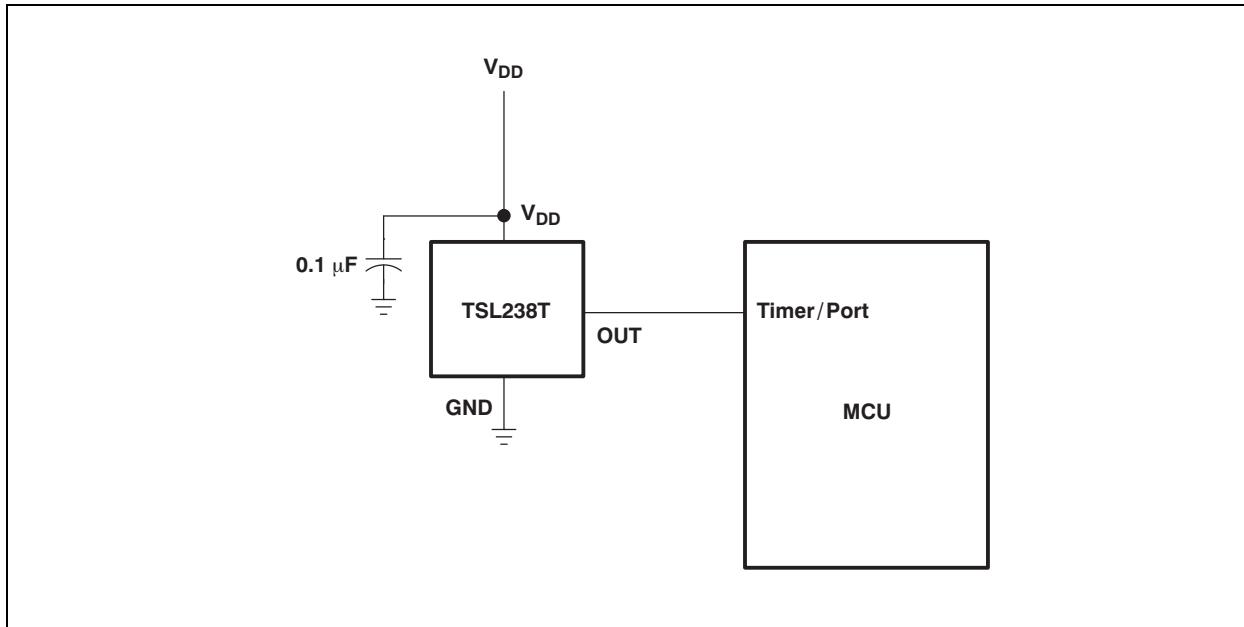


Application Information

Power-Supply Considerations

Power-supply lines must be decoupled by a 0.01- μ F to 0.1- μ F capacitor with short leads placed close to the TSL238T (Figure 17). A low-noise power supply is required to minimize jitter on output pulse.

Figure 17:
Typical TSL238T Interface to a Microcontroller



Device Operational Details

The frequency at the output pin (OUT) is given by:

$$(EQ1) \quad f_O = f_D + (R_e) \cdot (E_e)$$

where:

f_O is the output frequency

f_D is the output frequency for dark condition ($E_e = 0$)

R_e is the device responsivity for a given wavelength of light given in kHz/(μ W/cm²)

E_e is the incident irradiance in μ W/cm²

f_D is a constant error term in the output frequency calculation resulting from leakage currents, and is independent of light intensity. The TSL238T die is trimmed to minimize the magnitude of this dark frequency component so that it can be neglected in the transfer function calculation. In many applications, measurement of the actual dark frequency may

be impractical due to measurement times ranging from several seconds to several minutes, and the fact that some devices may never transition (zero dark frequency).

Output Interface

The output of the device is designed to drive a CMOS logic input over short distances. If lines greater than 12 inches in length are used on the output, a buffer or line driver is recommended.

Measuring the Frequency

The choice of interface and measurement technique depends on the desired resolution and data-acquisition rate. For maximum data-acquisition rate, period-measurement techniques are used.

Period measurement requires the use of a fast reference clock with available resolution directly related to the reference-clock rate. The technique is employed to measure rapidly varying light levels or to make a fast measurement of a constant light source.

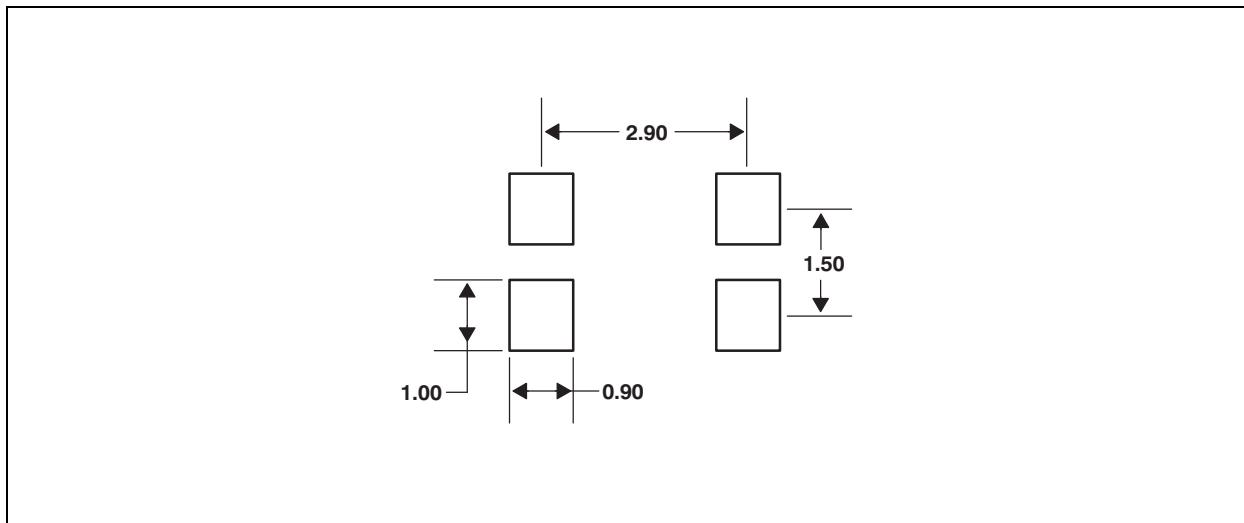
Maximum resolution and accuracy may be obtained using frequency-measurement, pulse-accumulation, or integration techniques. Frequency measurements provide the added benefit of averaging out random- or high-frequency variations (jitter) resulting from noise in the light signal. Resolution is limited mainly by available counter registers and allowable measurement time. Frequency measurement is well suited for slowly varying or constant light levels and for reading average light levels over short periods of time. Integration, the accumulation of pulses over a very long period of time, can be used to measure exposure — the amount of light present in an area over a given time period.

Output enable (\overline{OE}) places the output in a high-impedance state for multiple-unit sharing of a microcontroller input line. When the \overline{OE} line goes low, the device resynchronizes the output to an integration cycle. The rising edge of the output signal (OUT) will occur exactly one period of the output frequency after \overline{OE} goes low.

PCB Pad Layout

Suggested PCB pad layout guidelines for the T package are shown in [Figure 18](#).

Figure 18:
Suggested T Package PCB Layout



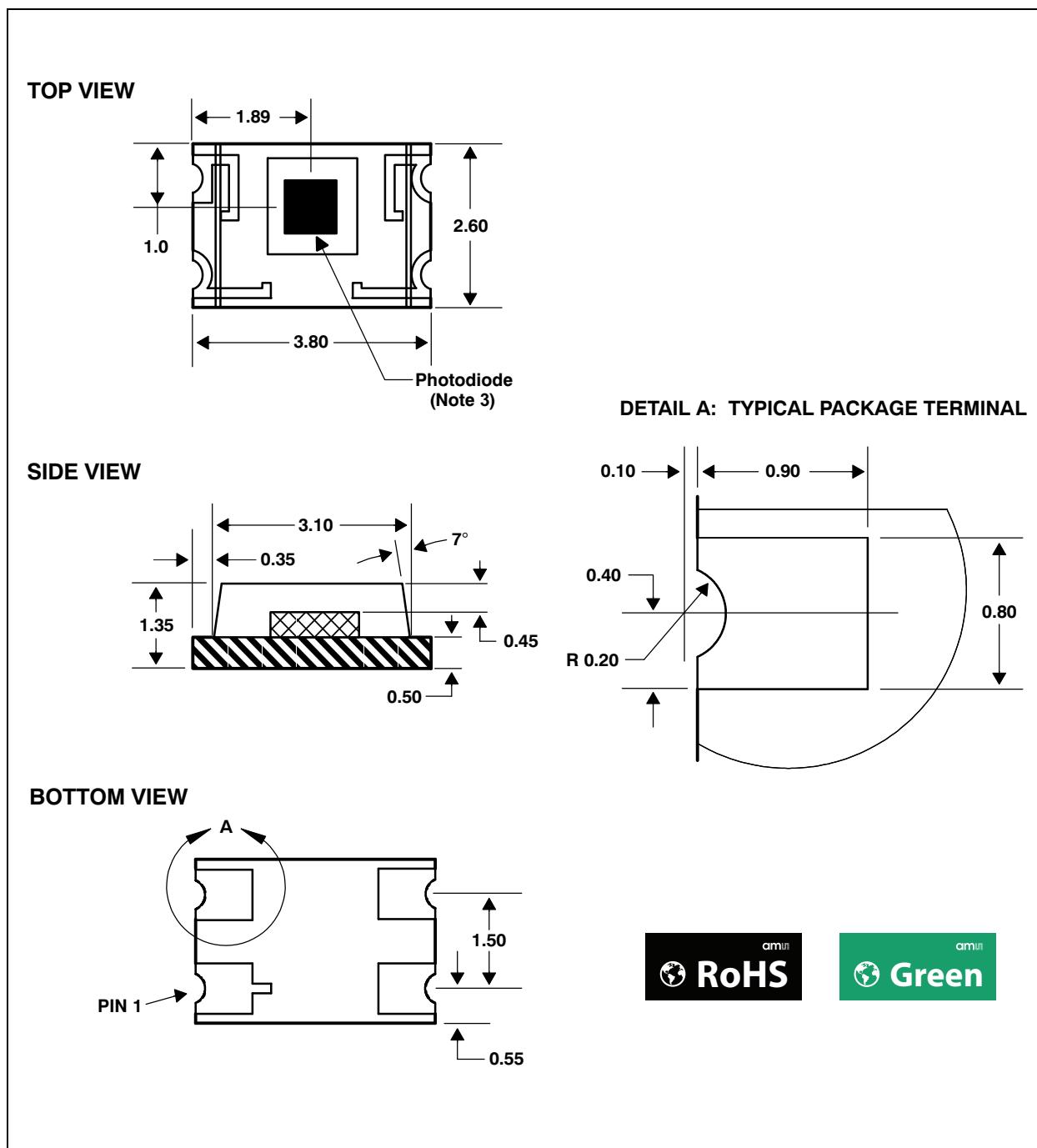
Note(s):

1. All linear dimensions are in millimeters.
2. This drawing is subject to change without notice.

Mechanical Data

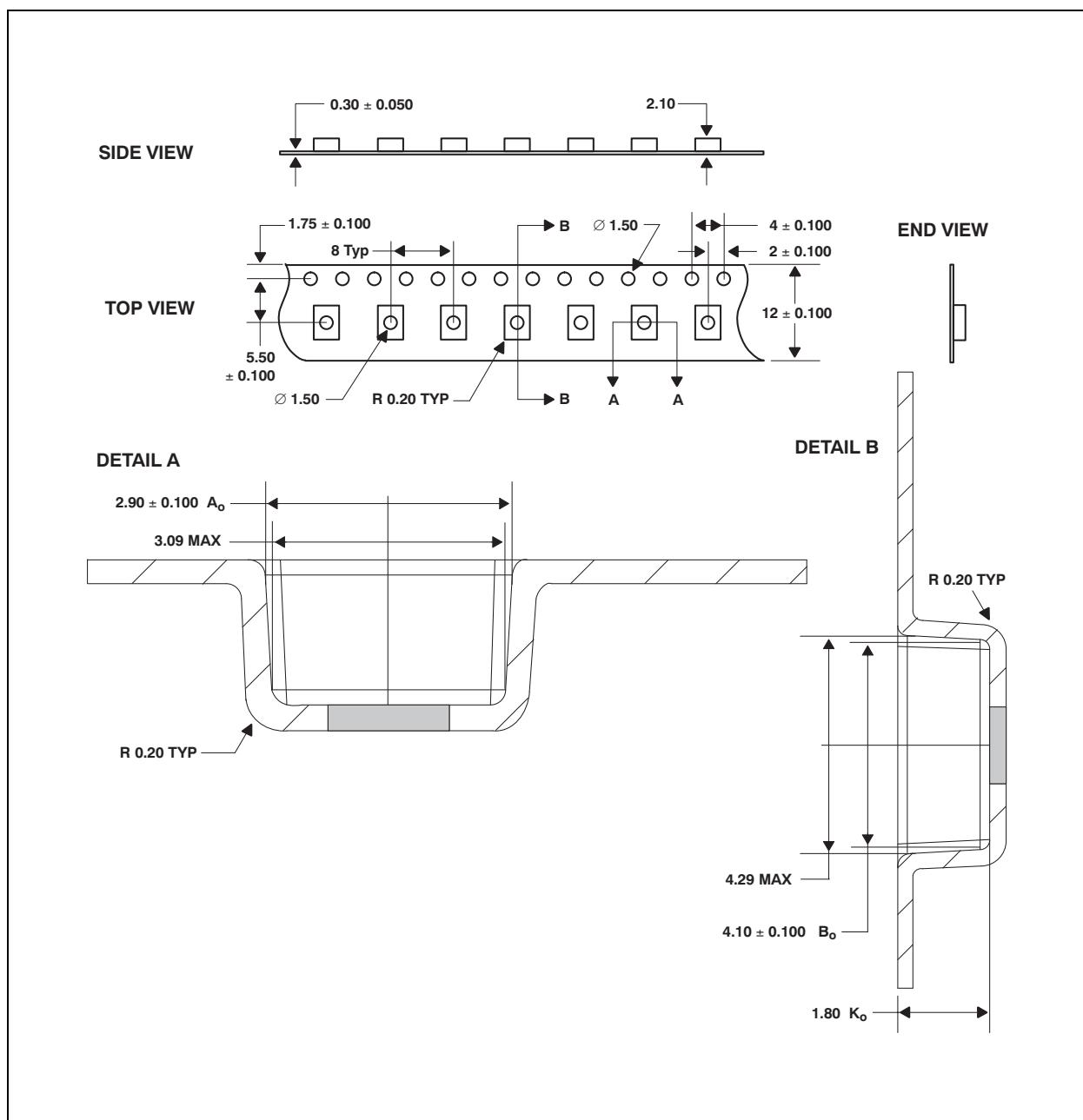
The TSL238T is supplied in a low-profile surface-mount package. This package contains no lead (Pb).

Figure 19:
Package T — Four-Lead Surface Mount Device Packaging Configuration

**Note(s):**

1. All linear dimensions are in millimeters.
2. Terminal finish is gold, 1.3 μm minimum.
3. The center of the 0.84-mm \times 0.84-mm photodiode active area is referenced to the upper left corner of the package (near Pin 1).
4. Dimension tolerance is ± 0.15 mm.
5. This drawing is subject to change without notice.

Figure 20:
Four Lead Surface Mount Package Carrier Tape



Note(s):

1. All linear dimensions are in millimeters.
2. The dimensions on this drawing are for illustrative purposes only. Dimensions of an actual carrier may vary slightly.
3. Symbols on drawing A_o , B_o , and K_o are defined in ANSI EIA Standard 481-B 2001.
4. Each reel is 178 millimeters in diameter and contains 1000 parts.
5. **ams** packaging tape and reel conform to the requirements of EIA Standard 481-B.
6. In accordance with EIA standard, device pin 1 is located next to the sprocket holes in the tape.
7. This drawing is subject to change without notice.

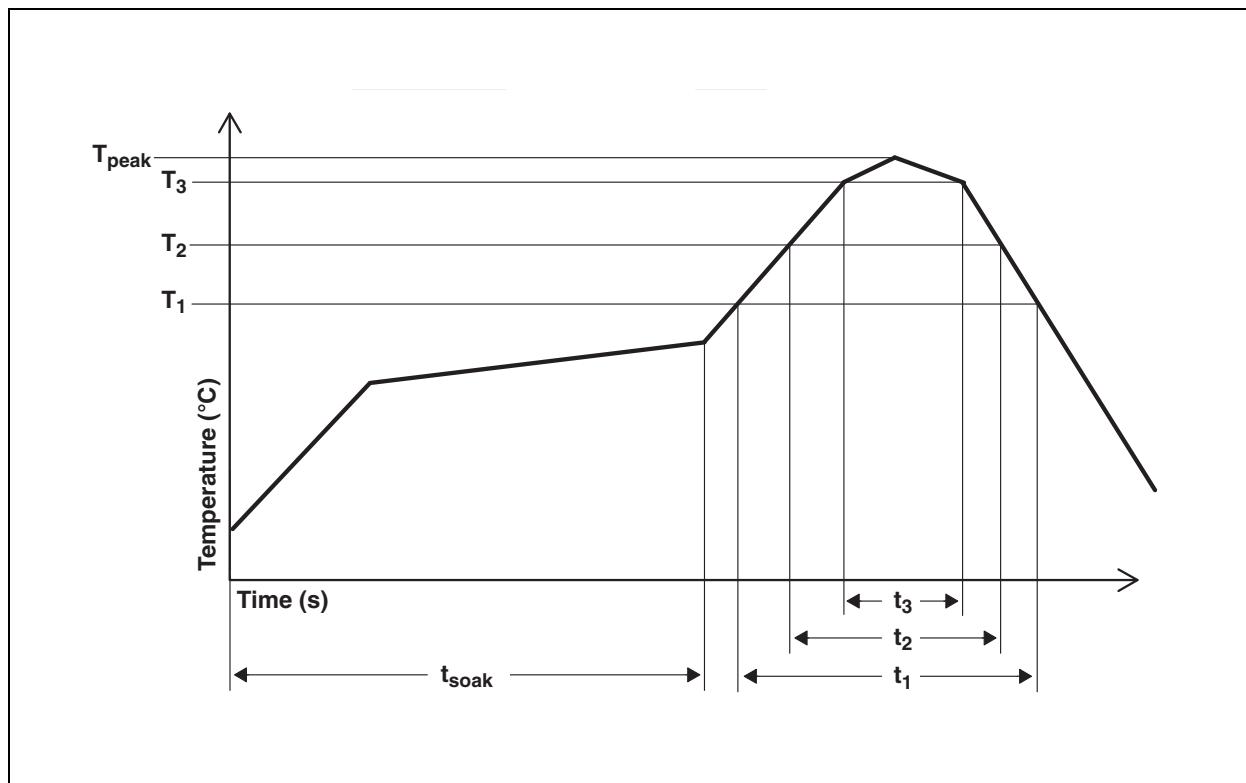
Manufacturing Information

The reflow profile specified here describes expected maximum heat exposure of devices during the solder reflow process of the device on a PWB. Temperature is measured at the top of the device. Devices should be limited to one pass through the solder reflow profile.

Figure 21:
TSL238T Solder Reflow Profile

Parameter	Reference	TSL238T
Average temperature gradient in preheating		2.5°C/s
Soak time	t_{soak}	2 to 3 minutes
Time above T_1 , 217°C	t_1	Max 60 s
Time above T_2 , 230°C	t_2	Max 50 s
Time above T_3 , ($T_{peak} - 10^\circ\text{C}$)	t_3	Max 10 s
Peak temperature in reflow	T_{peak}	260°C (-0°C/ 5°C)
Temperature gradient in cooling		Max -5°C/s

Figure 22:
TSL238T Solder Reflow Profile



Note(s):

1. This drawing is not to scale

Moisture Sensitivity

Optical characteristics of the device can be adversely affected during the soldering process by the release and vaporization of moisture that has been previously absorbed into the package molding compound. To ensure the package molding compound contains the smallest amount of absorbed moisture possible, each device is dry-baked prior to being packed for shipping. Devices are packed in a sealed aluminized envelope with silica gel to protect them from ambient moisture during shipping, handling, and storage before use.

This package has been assigned a moisture sensitivity level of MSL 3 and the devices should be stored under the following conditions:

- Temperature Range: 5°C to 50°C
- Relative Humidity: 60% maximum
- Total Time: 6 months from the date code on the aluminized envelope — if unopened
- Opened Time: 168 hours or fewer

Rebaking will be required if the devices have been stored unopened for more than 6 months or if the aluminized envelope has been open for more than 168 hours. If rebaking is required, it should be done at 90°C for 4 hours.

Ordering & Contact Information

Figure 23:
Ordering Information

Ordering Code	Device	T _A	Package – Leads	Package Designator
TSL238T	TSL238T	-40°C to 85°C	4-lead Low Profile Surface Mount	T

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Document Status

Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
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Revision Information

Changes from 080G (Dec-2007) to current revision 1-00 (2016-May-25)	Page
Content of TAOS datasheet was updated to latest ams design	
Updated Key Benefits & Features	1

Note(s):

1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision
2. Correction of typographical errors is not explicitly mentioned.

Content Guide

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